# 

#### **Data Sheet**

# AFBR-FS50B00

Transceiver for Optical Wireless Communications up to 5 Gb/s



#### Description

The Broadcom<sup>®</sup> AFBR-FS50B00 is a transceiver that communicates data over free space and thereby allows for wireless communication in a variety of applications.

Full-duplex bidirectional communication, together with a small form factor, allows a compact system design. The device keeps full functionality over a 360° rotation around the optical axis, which reduces the complexity of alignment at the system level.

The AFBR-FS50B00, a Laser Class 1 product, is RoHS compliant and is designed for SMT solderability standard processes.

#### Features

- Data rate: 125 Mb/s to 5 Gb/s
- Distance range: 30 mm to 100 mm
- Bidirectional full-duplex
- Full function over a 360° rotation
- Small form factor
- Single 3.3V power supply
- Operational temperature range: 0°C to +85°C
- SMT solderability
- RoHS compliant
- Laser Class 1

#### **Applications**

- Optical wireless communication
- Through-window optical wireless communication
- Rotary optical data feedthrough
- Board-to-board communication

#### Transmitter

The transmitter part of the AFBR-FS50B00 uses an 850-nm VCSEL. The VCSEL is driven by an IC, which converts differential input signals into an analog drive current. The transmitter IC can be enabled and disabled by means of the Tx EN pin.

#### Receiver

The receiver part of the AFBR-FS50B00 uses a high-speed PIN photodiode and an IC. The IC implements the functionality of a transimpedance amplifier followed by a limiting amplifier for the generation of the logical output. The data output is differential. The receiver IC provides a monitor current ( $I_{mon}$ ) output and a signal detect (SD) output.

#### **Block Diagram**

Figure 1: Transceiver Block Diagram

Figure 1 shows the block diagram of the transceiver. The transmitter and the receiver operate independent of each other.

# Differential Tx lines Tx IC VCSEL TxEN Differential Rx lines Rx IC PD

The product assembly consists of a carrier, the chipset (including the PD and VCSEL), and the lens. Figure 2 shows the geometry.

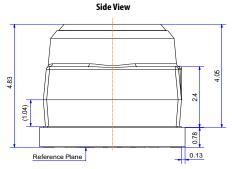
Figure 3 shows the 3D view of the transceiver. The central pad on the bottom side of the PCB is used for connecting to GND.

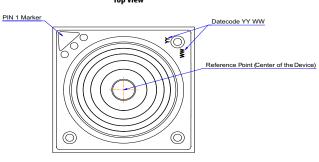
Figure 4 shows the pinout diagram of the transceiver with the location of the pins as seen from above (top view). Pin 1 is in the upper-left corner.

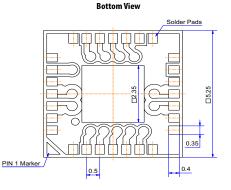
#### **Mechanical Dimensions**

Paramete	er	Value
Length	L	5.25 mm
Width	W	5.25 mm
Height	Н	4.83 mm

#### Figure 2: Package Outline Drawings



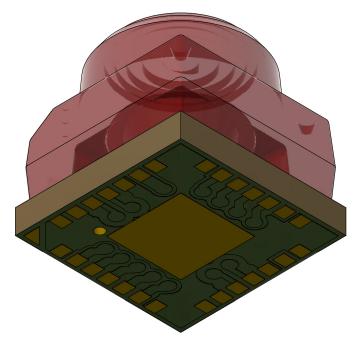


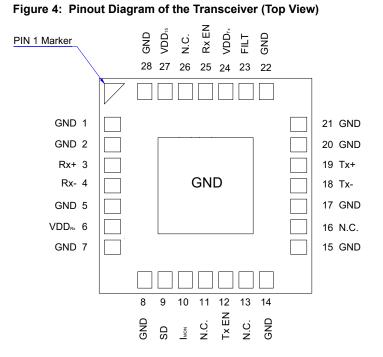


NOTE: Dimensions are in mm.

# Top View

#### Figure 3: 3D View of the Bottom Side of the Device





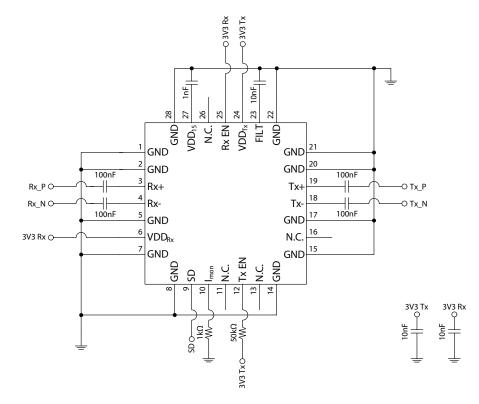
#### Table 2: Pin Descriptions

Pin	Name	I/O	Description	Pin	Name
1	GND	Supply	Ground	15	GND
2	GND	Supply	Ground	16	
3	Rx+	Out	Positive differential data output	17	GND
4	Rx-	Out	Negative differential data output	18	Tx-
5	GND	Supply	Ground	19	Tx+
6	VDD <sub>Rx</sub>	Supply	Rx power supply	20	GND
7	GND	Supply	Ground	21	GND
8	GND	Supply	Ground	22	GND
9	SD	Out	Signal Detect: Set to HIGH when a valid data signal is detected; LOW otherwise.	23	FILT
10	I <sub>mon</sub>	Out	Mirrored PD current	24	VDD <sub>Tx</sub>
11	_	—	N.C.	25	Rx EN
12	Tx EN	In	Activates the emitter driver— active HIGH.	26	—
13	—	—	N.C.	27	VDD <sub>15</sub>
14	GND	Supply	Ground	28	GND

Pin	Name	I/O	Description
15	GND	Supply	Ground
16	_	_	N.C.
17	GND	Supply	Ground
18	Tx-	In	Negative differential data input
19	Tx+	In	Positive differential data input
20	GND	Supply	Ground
21	GND	Supply	Ground
22	GND	Supply	Ground
23	FILT	In/Out	Power supply decoupling (Tx)
24	VDD <sub>Tx</sub>	Supply	Tx power supply
25	Rx EN	In	Activates the receiver IC—active HIGH.
26	—	—	N.C.
27	VDD <sub>15</sub>	Supply	This pin must be left open or connected to a 1-nF capacitor (recommended value).
28	GND	Supply	Ground

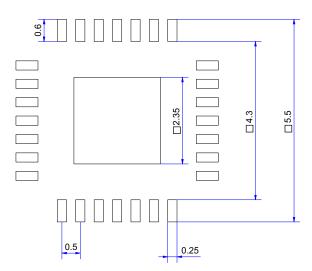
## **Typical Application Circuit**

Figure 5: Schematic of a Typical Application Circuit



#### **Recommended PCB Layout**

Figure 6: Recommended PCB Solder Pads



**NOTE:** Values are in mm.

### **Solder Process Profile**

Figure 7 shows the recommended temperature profile over time for lead-free solder pastes. The maximum temperature of +245°C for a maximum time of 10-second peak must not be exceeded. Higher temperatures will permanently damage the device. Heating by IR sources is not allowed due to the additional self-heating effect.

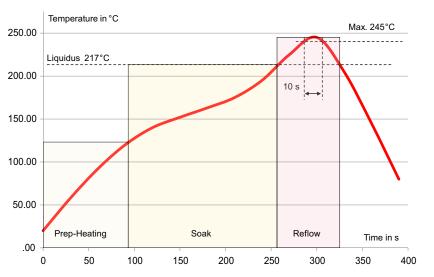


Figure 7: Example of a Recommended Reflow Temperature Profile for a Lead-Free Solder Paste

### **Electrostatic Discharge**

Follow common ESD handling precautions for ESD-sensitive devices. These precautions include using grounded wrist straps, work benches, and floor mats in ESD-controlled areas.

#### Immunity

Equipment that hosts the AFBR-FS50B00 might be subjected to radio-frequency electromagnetic fields in some environments. The transceiver has good immunity to such fields due to its compact design.

## **Regulatory Compliance**

#### Table 3: Regulatory Compliance

Feature	Test Method	Performance
Electrostatic Discharge (ESD)	JEDEC JS-001-2012	HBM 1 kV.
Immunity	EN 55024 EN 61000-4-3	Typically shows no measurable effect from a 10V/m field swept from 80 MHz to 6 GHz applied to the transceiver without enclosure.
Eye Safety	IEC/EN 60825-1:2014	Class 1 laser safety.
EMI	EN55032 EN55016-2-3	System margins are dependent on customer board design.
RoHS I and II Compliance	_	Refer to RoHS Directive 2011/65EU Annex II and RoHS RL (EU) 2015-863.

## **Absolute Maximum Ratings**

Stresses in excess of the absolute maximum ratings can cause catastrophic damage to the device. Limits apply to each parameter in isolation, with all other parameters having values within the recommended operation conditions. Exposure to the absolute maximum ratings for extended periods can adversely affect device reliability.

Parameter	Symbol	Min.	Max.	Unit	Notes
Storage Temperature	T <sub>s</sub>	0	85	°C	_
Transmitter Supply Voltage	VDD <sub>Tx</sub>	-0.5	4.5	V	—
Receiver Supply Voltage	VDD <sub>Rx</sub>	-0.4	4.0	V	—
Data Input Voltage at Tx+/Tx–	Vi	-0.5	1.8	V	_
Soldering Temperature	T <sub>sold</sub>	—	+245	°C	a, b
Soldering Time	t <sub>sold</sub>	_	10	seconds	a, b
Total Power Dissipation	—	—	120	mW	_

a. MSL 5a.

b. According to Figure 7.

### **Recommended Operating Conditions**

All data in this specification refers to the preceding operating conditions.

Parameter	Symbol	Min.	Тур.	Max.	Unit	Notes
Ambient Operating Temperature	T <sub>c</sub>	0	25	85	°C	а
Transmitter Supply Voltage	VDD <sub>Tx</sub>	3.13	3.3	3.47	V	_
Receiver Supply Voltage	VDD <sub>Rx</sub>	3.13	3.3	3.47	V	—
Data Rate	DR	0.125	—	5	Gb/s	b
Link Distance	D <sub>Link</sub>	30		100	mm	c, d

a. The electrical and optical specifications of the product are guaranteed across the recommended ambient operating temperature range only.

b. The maximum lateral misalignment from transceiver to transceiver is 1 mm from the reference point (see Figure 2) of Transceiver 1 to the reference point of Transceiver 2 at a link distance of 60 mm. In this condition, a BER <  $10^{-9}$  can be reached for 8b10b coding and 5 Gb/s. The reference planes (see Figure 2) of the two transceivers of the optical link must be parallel to each other.

c. Top of lens to top of lens.

d. For distances above 60 mm, special care must be taken to avoid additional tilt while soldering the device and assembling in the system.

#### **Transmitter Electrical Characteristics**

Typical values are for room temperature at 3.3V and 5 Gb/s.

Parameter	Symbol	Min.	Тур.	Max.	Unit	Notes
Supply Current	Tx I <sub>CC</sub>	_	5	8.5	mA	_
Common Mode Input Voltage	V <sub>ICM</sub>	150	—	340	mV	_
Differential Input Voltage (p-p)	V <sub>Din</sub>	0.2	_	1.4	V	а
Differential Input Impedance	Z <sub>in</sub>	90	100	110	Ω	b
Transmitter Enable Input, HIGH	V <sub>TxEN,H</sub>	$0.4 \times VDD_{Tx}$	—	VDD <sub>Tx</sub>	V	_
Transmitter Enable Input, LOW	V <sub>TxEN,L</sub>	0	_	0.4	V	—

a. LVPECL AC coupled.

b. Self-biasing differential input; input signal must be AC coupled.

### **Transmitter Optical Characteristics**

Parameter	Symbol	Min.	Тур.	Max.	Unit	Notes
Central Wavelength	$\lambda_{c}$	830	850	870	nm	—
Spectral Width – FWHM	Δλ	—	0.40	0.85	nm	_

#### **Receiver Electrical Characteristics**

Typical values are for room temperature at 3.3V and 5 Gb/s.

Parameter	Symbol	Min.	Тур.	Max.	Unit	Notes
Supply Current	Rx I <sub>CC</sub>	_	19	26	mA	_
Common Mode Output Voltage	V <sub>OCM</sub>	180	250	330	mV	_
Differential Output Voltage (p) or Vp	V <sub>Dout</sub>	0.18	0.23	0.33	V	а
Differential Output Impedance	Z <sub>out</sub>	90		110	Ω	
Data Output Rise Time (10% to 90%)	t <sub>r</sub>	—	—	95	ps	b
Data Output Fall Time (90% to 10%)	t <sub>f</sub>	_	_	95	ps	b
Signal Detect Output Voltage, LOW	SD <sub>O,L</sub>	—	—	0.1	V	с
Signal Detect Output Voltage, HIGH	SD <sub>O,H</sub>	1.1	1.5	1.55	V	d

a. With a  $100\Omega$  differential load and AC coupling of the output signal.

b. No capacitive load,  $50\Omega$  terminated to GND.

c. The Signal Detect pin will output a LOW voltage level if  $I_{mon} \le 1 \ \mu$ A.

d. The Signal Detect pin will output a HIGH voltage level if  $I_{mon} \ge 3 \ \mu A$ .

#### **Receiver Optical Characteristics**

Parameter	Symbol	Min.	Тур.	Max.	Unit	Notes
Operating Wavelength	$\lambda_{c}$	830	850	860	nm	—

# **Optical Link Performance**

Parameter	Symbol	Min.	Тур.	Max.	Unit	Notes
Bit Error Rate	BER		_	2.5 × 10 <sup>-10</sup>		a, b, c
Total Jitter at the Rx at 5 Gb/s	T <sub>j</sub> Rx			0.35	UI	a, b, d

a. In air.

b. Tested with 8b10b.

c.  $2.5 \times 10^{-10}$  for perfect alignment.

d. Total jitter of the full link with an ideal electrical signal at the input of the Tx.

#### **Typical Lateral Misalignment Tolerance**

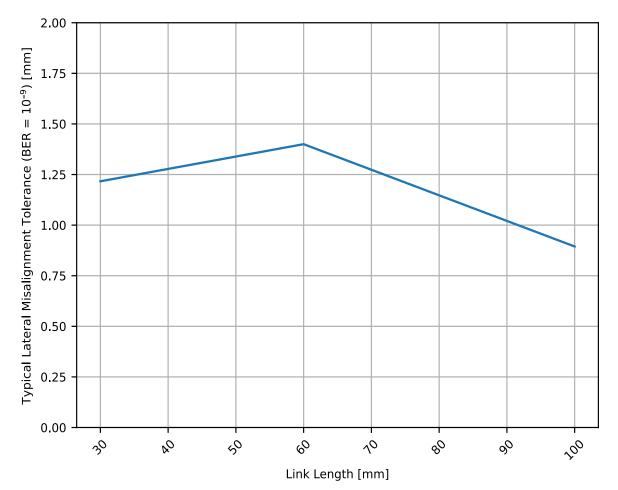


Figure 8: Typical Lateral Misalignment Tolerance (BER = 10<sup>-9</sup>) vs. Link Length, Measured at 5 Gb/s

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